



PATENT APPLICATION
Docket No. 2522-040
Client No. AW8072US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Jae-Jong Han, et al. Conf. No. 9537
Serial No. 10/672,884 Examiner: Lee, Hsien Ming
Filed: September 26, 2003 Art Unit: 2823
For: METHOD OF FORMING A GATE ELECTRODE, METHOD OF
MANUFACTURING A SEMICONDUCTOR DEVICE HAVING
THE GATE ELECTRODE, AND METHOD OF OXIDIZING A
SUBSTRATE

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

This Information Disclosure Statement is submitted:

- ☒ under 37 CFR 1.97 (c) together with either a:
☒ Statement under 37 CFR 1.97 (e), or
☐ a \$180 fee under 37 CFR 1.17 (p); or
(After mailing of first Office Action, but prior to Notice of Allowance or Final Office Action)
☒ Applicant(s) submit herewith Form PTO 1449- Information Disclosure Citation together with copies of patents, publications or other information of which applicant(s) are aware, which applicant(s) believe(s) may be material to the examination of this application and for which there may be a duty to disclose in accordance with 37 CFR 1.56.

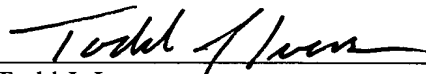
It is requested that the information disclosed herein be made of record in this application.

Any deficiency or overpayment should be charged or credited to deposit account number 13-1703.

Customer No. 20575

Respectfully submitted,

MARGER JOHNSON & McCOLLOM, P.C.


Todd J. Iverson
Reg. No. 53,057

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I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Mail Stop Amendment
Commissioner for Patents, P.O. Box 1450,
Alexandria, VA 22313-1450
Date: September 16, 2004


Li Mei Vermilya



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INFORMATION DISCLOSURE CITATION
FORM PTO-1449 (Modified)

FOREIGN PATENT DOCUMENTS

<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Publication</u> <u>Number</u>	<u>Publication</u> <u>Date</u>	<u>Country</u>	<u>Name</u>
_____	_____	000061321 A	Oct. 16, 2000	Korea	EOM, et al.

OTHER DOCUMENTS

<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Author, Title, Date, Pertinent Pages, Etc.)</u>
_____	_____	English Language Abstract of Korean Publication No: 000061321 A

Examiner: _____

Date Considered: _____



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STATEMENT ON FILING INFORMATION DISCLOSURE STATEMENT
(37 CFR 1.97(e))

I, Todd J. Iverson, the person signing below state that:

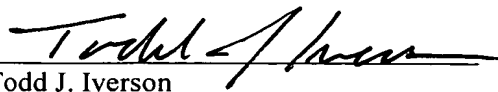
Each item of information contained in the Information Disclosure Statement submitted herewith was first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this Statement

Applicant respectfully requests consideration of the accompanying Information Disclosure Statement.

The person making this Statement is the attorney who signs below on the basis of the information in the attorney's file.

Respectfully submitted,

MARGER JOHNSON & McCOLLOM, P.C.


Todd J. Iverson
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